

# Power transistor (60V, 2A)

## 2SC5880

### ●Features

- 1) High speed switching.  
(Tf : Typ. : 35ns at Ic = 2A)
- 2) Low saturation voltage, typically  
(Typ. : 200mV at Ic = 1.0A, IB = 100mA)
- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SA2093

### ●Applications

Low frequency amplifier  
High speed switching

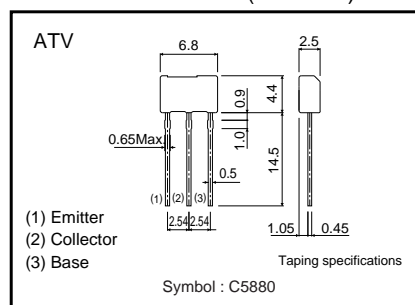
### ●Structure

NPN Silicon epitaxial planar transistor

### ●Packaging specifications

Type	Package	Taping
	Code	TV2
	Basic ordering unit (pieces)	2500
2SC5880		○

### ●External dimensions (Unit : mm)



### ●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Collector-base voltage		V <sub>CB0</sub>	60	V
Collector-emitter voltage		V <sub>CE0</sub>	60	V
Emitter-base voltage		V <sub>EB0</sub>	6	V
Collector current	DC	I <sub>C</sub>	2	A
	Pulsed	I <sub>CP</sub>	4	A *
Power dissipation		P <sub>C</sub>	1.0	W
Junction temperature		T <sub>J</sub>	150	°C
Range of storage temperature		T <sub>stg</sub>	-55 to 150	°C

\*Pw=10ms

## Transistors

## ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Collector-emitter breakdown voltage	$BV_{CEO}$	60	—	—	V	$I_C=1\text{mA}$
Collector-base breakdown voltage	$BV_{CBO}$	60	—	—	V	$I_C=100\mu\text{A}$
Emitter-base breakdown voltage	$BV_{EBO}$	6	—	—	V	$I_E=100\mu\text{A}$
Collector cut-off current	$I_{CBO}$	—	—	1.0	$\mu\text{A}$	$V_{CB}=40\text{V}$
Emitter cut-off current	$I_{EBO}$	—	—	1.0	$\mu\text{A}$	$V_{EB}=4\text{V}$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	200	500	mV	$I_C=1.0\text{A}$ $I_B=0.1\text{A}$
DC current gain	$h_{FE}$	120	—	390	—	$V_{CE}=2\text{V}$ $I_C=100\text{mA}$
Transition frequency	$f_T$	—	200	—	MHz	$V_{CE}=10\text{V}$ $I_E=-100\text{mA}$ $f=10\text{MHz}$
Corrector output capacitance	$C_{ob}$	—	10	—	pF	$V_{CB}=10\text{V}$ $I_E=0\text{mA}$ $f=1\text{MHz}$
Turn-on time	$T_{on}$	—	50	—	ns	$I_C=2\text{A}$ $I_{B1}=200\text{mA}$
Storage time	$T_{stg}$	—	120	—	ns	$I_{B2}=-200\text{mA}$
Fall time	$T_f$	—	35	—	ns	$V_{CC}\approx 25\text{V}$

\*Non repetitive pulse

● $h_{FE}$  RANK

Q	R
120–270	180–390

## ●Electrical characteristic curves

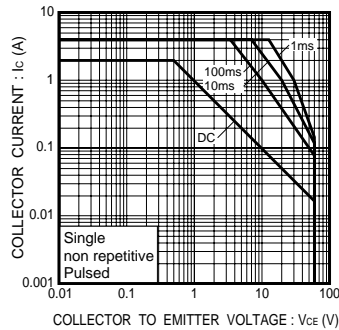


Fig.1 Safe Operating Area

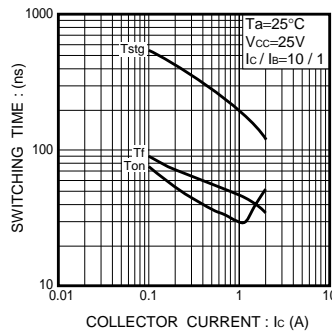


Fig.2 Switching Time

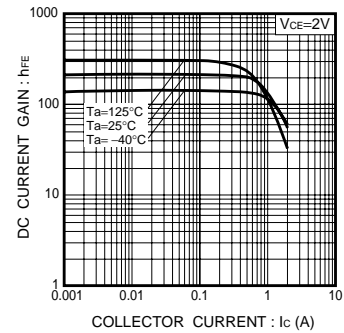


Fig.3 DC Current Gain vs. Collector Current (I)

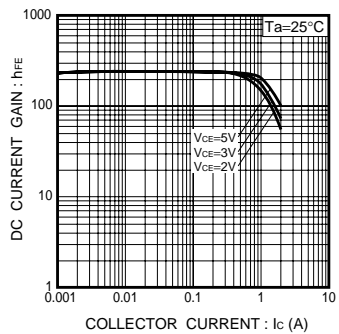


Fig.4 DC Current Gain vs. Collector Current (II)

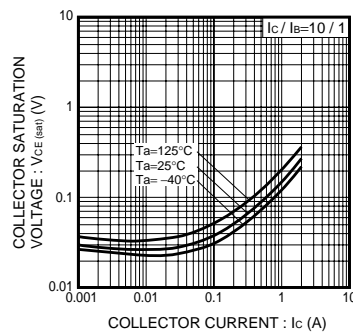


Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

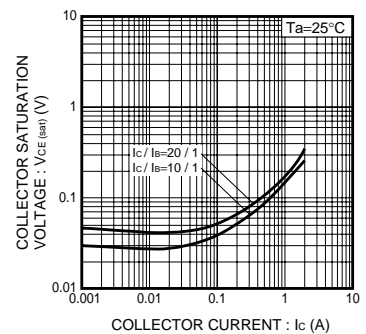


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)

## Transistors

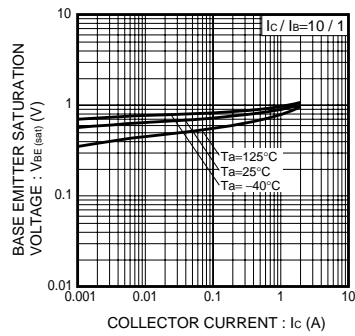


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

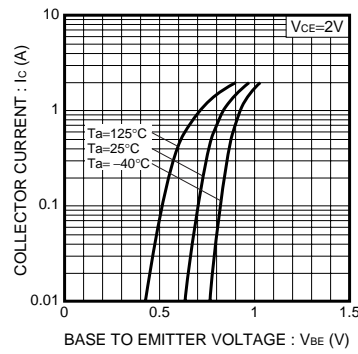


Fig.8 Grounded Emitter Propagation Characteristics

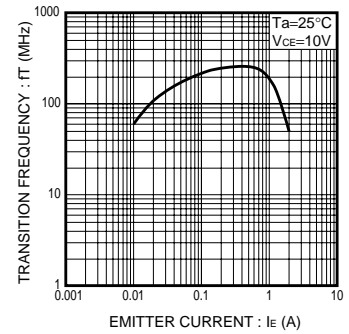


Fig.9 Transition Frequency

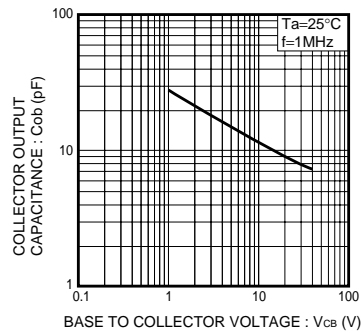
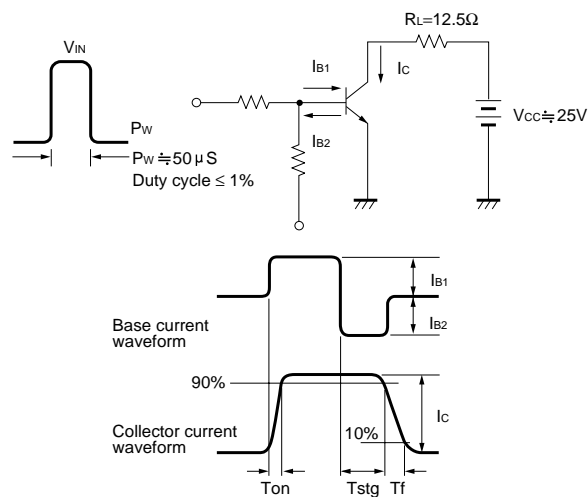


Fig.10 Collector Output Capacitance

●Switching characteristics measurement circuits



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